Jun. 2017



SDA60-10S 60A, 1000V Standard Rectifier

Features

• Typical Forward Voltage: V_F=0.95V@ I_F=60A

• Reverse Voltage: V_{RRM} =1000V

Avalanche Energy Rated

· SIPOS+GPP double passivation

Applications

- · Diode for main rectification
- For single and three phase
- · Bridge configurations

Description

The SDA60-10S is a Standard Rectifier. It's a SIPOS+GPP double passivation chip, with high reliability. It has low leakage current and low forward voltage drop, Improved thermal behaviour

Package Type & Internal Circuit





1. Anode 2.Cathode

Absolute Maximum Ratings per diode at T_C=25 ℃ unless otherwise noted

Symbol	Parameter			Ratings	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage			1000	V	
V _{RWM}	Working Peak Reverse Voltage			1000	V	
V _R	DC Blocking Voltage			1000	V	
I _{F(AV)}	Average Rectified Forward Current	per device at To	;=120°C	60	А	
	Non repetitive Deak Surge Current	t = 10 ms	T _{VJ} = 45° C V _R = 0 V	720	A	
^I FSM	Non-repetitive Peak Surge Current	(50 Hz), sine	T _{VJ} = 150° C V _R = 0 V	540	A	
2t	value for fusing	t = 10 ms	T _{VJ} = 45° C V _R = 0 V	2580	A ² S	
1 - 1		(50 Hz), sine	T _{VJ} = 150° C V _R = 0 V	1450		
T _J	Operating Junction Temperature Range			-40~+150	°C	
T _{STG}	Storage Temperature Range			-40~+150	°C	

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Thermal Characteristics

Symbol	Parameter	Ratings	Unit	
R _{th (J-C)}	Thermal Resistance, Junction to case	0.32	°C/W	

$\textbf{Electrical Characteristics} \text{ per diode } @T_{\text{C}}\text{=}25 \text{ } ^{\circ}\text{C} \text{ unless otherwise noted}$

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V	Forward Voltage Drop	I _F =60A	-	0.95	1.2	V
V _F		I _F =60A, T _C =120℃	-		0.95	V
I _R	Reverse Leakage Current	V _R =1000V	-	-	1	mA

Typical Performance Characteristics

Fig. 1. Typical Characteristics: V_F vs. I_F

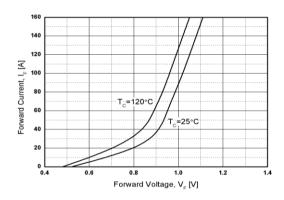


Fig. 2. Typical Characteristics: V_R vs. I_R

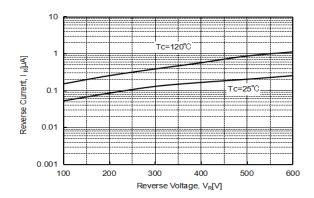
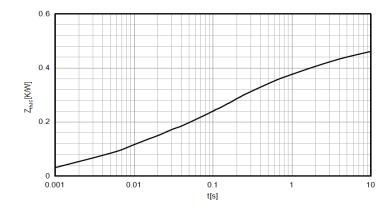


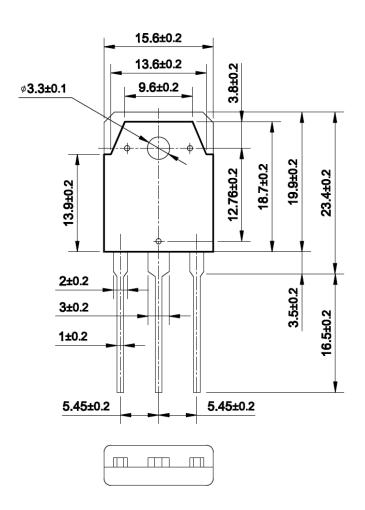
Fig. 3. Transient thermal impedance junction to case



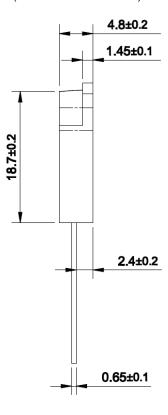


Package Dimensions

TO-3PN



(Dimensions in Millimeters)



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